



RGP10A THRU RGP10M

1.0 AMP. Glass Passivated Junction Fast Recovery Rectifiers



Voltage Range
50 to 1000 Volts
Current
1.0 Ampere

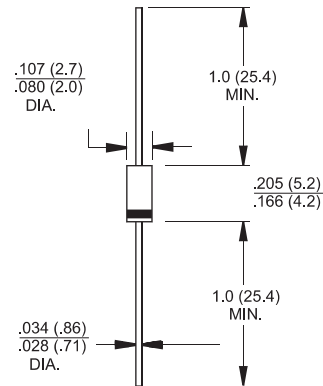
Features

- ✦ High temperature metallurgically bonded constructed
- ✦ Plastic material used carries Underwriters Laboratory Classification 94V-0
- ✦ Glass passivated cavity-free junction
- ✦ Capable of meeting environmental standards of MIL-S-19500
- ✦ 1.0 ampere operation at $T_A=55^\circ\text{C}$ with no thermal runaway
- ✦ Typical I_R less than 0.1 μA
- ✦ High temperature soldering guaranteed:
350°C / 10 seconds, 0.375" (9.5mm) lead length, 5 lbs., (2.3kg) tension
- ✦ Fast switching for high efficiency

Mechanical Data

- ✦ Case: JEDEC DO-41 molded plastic over glass body
- ✦ Lead: Plated Axial leads, solderable per MIL-STD-750, Method 2026
- ✦ Polarity: Color band denotes cathode end
- ✦ Mounting position: Any
- ✦ Weight: 0.012 ounce, 0.3 gram

DO-41



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	RGP 10A	RGP 10B	RGP 10D	RGP 10G	RGP 10J	RGP 10K	RGP 10M	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current .375" (9.5mm) Lead Length @ $T_A = 55^\circ\text{C}$	$I_{(AV)}$	1.0							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	30.0							A
Maximum Instantaneous Forward Voltage @ 1.0A	V_F	1.3							V
Maximum DC Reverse Current @ $T_A=25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A=150^\circ\text{C}$	I_R	5.0 200							μA μA
Maximum Reverse Recovery Time (Note 1) $T_J=25^\circ\text{C}$	T_{rr}	150				250	500		nS
Typical Junction Capacitance (Note 2)	C_j	15							pF
Typical Thermal Resistance (Note 3)	$R_{\theta JA}$	65							$^\circ\text{C}/\text{W}$
Operating Temperature Range	T_J	-65 to + 175							$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-65 to + 175							$^\circ\text{C}$

Notes: 1. Reverse Recovery Test Conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$ Recover to 0.25A.

2. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0 Volts.

3. Mount on Cu-Pad Size 5mm x 5mm on P.C.B.

RATINGS AND CHARACTERISTIC CURVES (RGP10A THRU RGP10M)

FIG.1- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

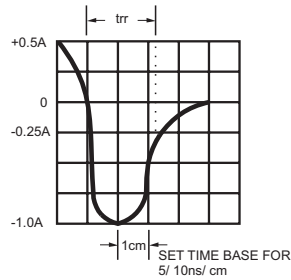
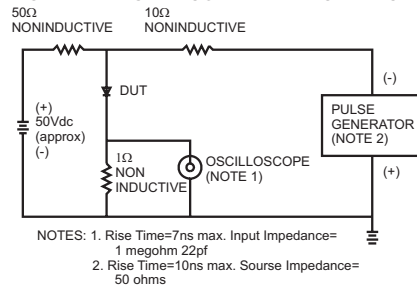


FIG.2- MAXIMUM FORWARD CURRENT DERATING CURVE

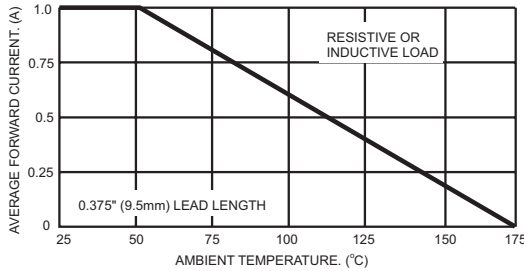


FIG.3- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

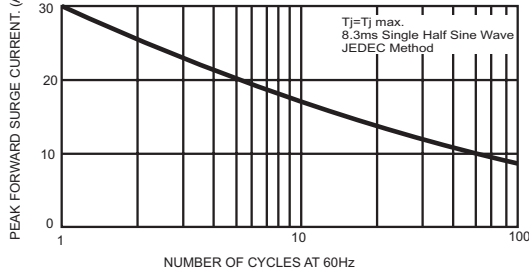


FIG.4- TYPICAL JUNCTION CAPACITANCE

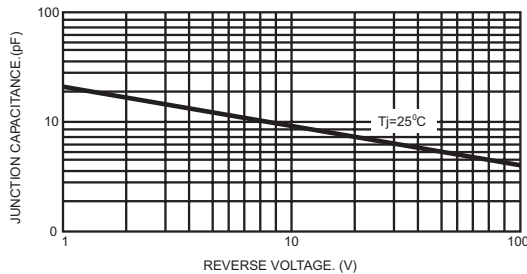


FIG.5- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

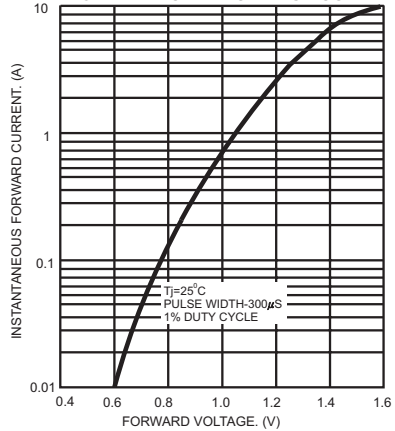
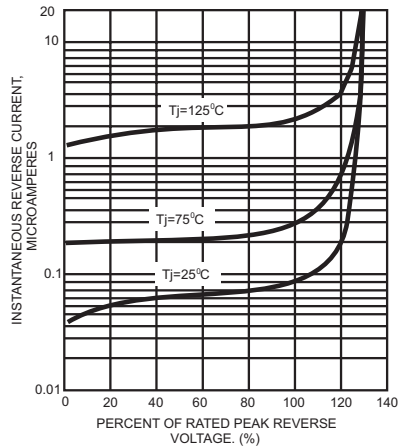


FIG.6- TYPICAL REVERSE CHARACTERISTICS



Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Taiwan Semiconductor:](#)

[RGP10G](#) [RGP10B](#) [RGP10J](#) [RGP10A](#) [RGP10K](#)